DM5426/DM7426 Quad 2-Input NAND Gates with High Voltage Open-Collector Outputs

# DM5426/DM7426 Quad 2-Input NAND Gates with High Voltage Open-Collector Outputs

## **General Description**

This device contains four independent gates each of which performs the logic NAND function. The open-collector outputs require external pull-up resistors for proper logical operation

## **Pull-Up Resistor Equations**

$$R_{MAX} = \frac{V_{O} (Min) - V_{OH}}{N_{1} (I_{OH}) + N_{2} (I_{IH})}$$

$$R_{MIN} = \frac{V_{O} (Max) - V_{OL}}{I_{OL} - N_{3} (I_{IL})}$$

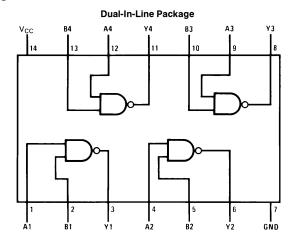
Where:  $N_1$  ( $I_{OH}$ ) = total maximum output high current for all outputs tied to pull-up resistor

 $N_2 \; (I_{IH}) = total \; maximum \; input high current for all inputs tied to pull-up resistor$ 

 $N_3 \ (I_{IL}) = total \ maximum \ input low current for all inputs tied to pull-up resistor$ 

TL/F/6508-1

## **Connection Diagram**



Order Number DM5426J or DM7426N See NS Package Number J14A or N14A

#### **Function Table**

H = High Logic Level

L = Low Logic Level

#### **Absolute Maximum Ratings (Note)**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 5.5V
Output Voltage 15V

Operating Free Air Temperature Range

 DM54
 -55°C to +125°C

 DM74
 0°C to +70°C

 Storage Temperature Range
 -65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

## **Recommended Operating Conditions**

Symbol	Parameter	DM5426		DM7426			Units	
		Min	Nom	Max	Min	Nom	Max	
V <sub>CC</sub>	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Voltage	2			2			V
V <sub>IL</sub>	Low Level Input Voltage			0.8			0.8	V
V <sub>OH</sub>	High Level Output Voltage			15			15	V
l <sub>OL</sub>	Low Level Output Current			16			16	mA
T <sub>A</sub>	Free Air Operating Temperature	-55		125	0		70	°C

### **Electrical Characteristics**

over recommended operating free air temperature range (unless otherwise noted)

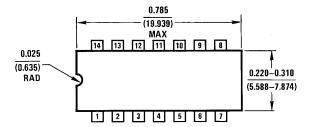
Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_{I} = -12 \text{ mA}$			-1.5	٧
I <sub>CEX</sub>	High Level Output Current	$V_{CC} = Min$ $V_O = 15V$			1000	μΑ
		$V_{IL} = Max$ $V_O = 12V$			50	
V <sub>OL</sub>	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$			0.4	V
lı	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			1	mA
I <sub>IH</sub>	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$			40	μΑ
I <sub>I</sub> L	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-1.6	mA
Іссн	Supply Current with Outputs High	V <sub>CC</sub> = Max		4	8	mA
I <sub>CCL</sub>	Supply Current with Outputs Low	V <sub>CC</sub> = Max		12	22	mA

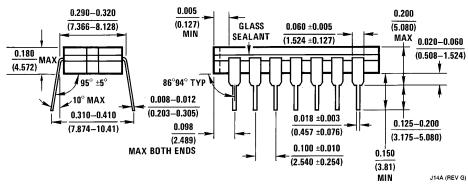
## $\textbf{Switching Characteristics} \text{ at V}_{CC} = 5 \text{V and T}_{A} = 25 ^{\circ}\text{C (See Section 1 for Test Waveforms and Output Load)}$

Symbol	Parameter	Conditions	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	$C_L = 15 \text{ pF}$ $R_L = 1 \text{ k}\Omega \text{ (t}_{PLH}\text{)}$		24	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output			17	ns

Note 1: All typicals are at  $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ .

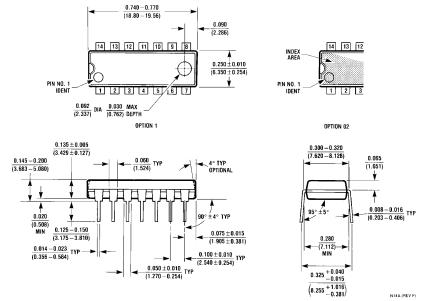






14-Lead Ceramic Dual-In-Line Package (J) Order Number DM5426J NS Package Number J14A

## Physical Dimensions inches (millimeters) (Continued)



14-Lead Molded Dual-In-Line Package (N) Order Number DM7426N NS Package Number N14A

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